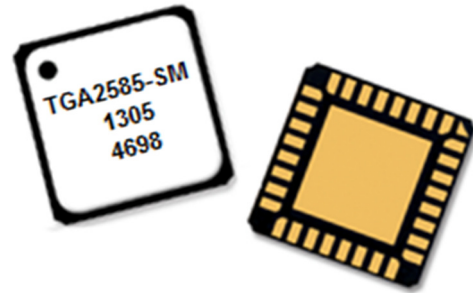


## Applications

- Commercial and Military Radar

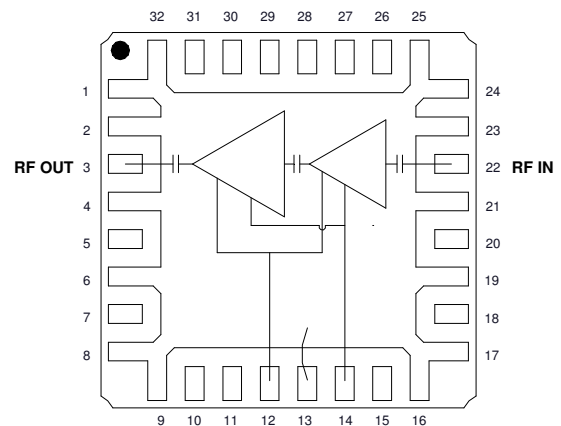


QFN 5x5 mm 32L

## Product Features

- Frequency Range: 2.7 - 3.7 GHz
- $P_{SAT}$ : 42.5 dBm
- PAE: > 50 %
- Small Signal Gain: 32 dB
- Return Loss: > 10 dB
- Bias:  $V_D = 28$  V (CW or Pulsed),  $I_{DQ} = 225$  mA,  $V_G = -2.5$  V Typical
- Package Dimensions: 5.0 x 5.0 x 1.45 mm

## Functional Block Diagram



## General Description

TriQuint's TGA2585-SM is a packaged MMIC power amplifier which operates from 2.7 to 3.7 GHz. The TGA2585-SM is designed using TriQuint's production 0.25- $\mu$ m GaN on SiC process.

The TGA2585-SM typically provides 42.5 dBm of saturated output power, > 50% power-added efficiency, and 32 dB small signal gain. It can operate under both pulse and CW conditions.

The TGA2585-SM is available in a low-cost, surface mount 32 lead 5x5 AIN QFN. It is ideally suited to support both commercial and defense related radar applications.

Both RF ports have integrated DC blocking capacitors and are fully matched to 50 ohms.

Lead-free and RoHS compliant

Evaluation Boards are available upon request.

## Pin Configuration

Pad No.	Symbol
1, 3-4, 6, 8-9, 13, 16-17, 19, 21, 23-25, 32	GND
3	RF OUT
5, 7, 10-11, 15, 18, 20, 26-31	NC
12	DRAIN
14	GATE
22	RF IN

## Ordering Information

Part	ECCN	Description
TGA2585-SM	EAR99	2.7 - 3.7 GHz, 18 W GaN Power Amplifier

### Absolute Maximum Ratings

Parameter	Value
Drain Voltage ( $V_D$ )	40 V
Gate Voltage Range ( $V_G$ )	-8 to 0 V
Drain Current ( $I_D$ )	1530 mA
Gate Current ( $I_G$ )	-7 to 11.5 mA
Power Dissipation ( $P_{DISS}$ ), 85 °C	35 W
Input Power ( $P_{IN}$ ), CW, 50 $\Omega$ , 85 °C	30 dBm
Input Power ( $P_{IN}$ ), CW, VSWR 10:1, $V_D = 28$ V, 85 °C	23 dBm
Channel Temperature ( $T_{CH}$ )	275 °C
Mounting Temperature (30 Seconds)	260 °C
Storage Temperature	-55 to 150 °C

Operation of this device outside the parameter ranges given above may cause permanent damage. These are stress ratings only, and functional operation of the device at these conditions is not implied.

### Recommended Operating Conditions

Parameter	Value
Drain Voltage ( $V_D$ )	28 V
Drain Current ( $I_{DQ}$ )	225 mA
Drain Current Under RF Drive ( $I_{D\_DRIVE}$ )	See plots p. 7
Gate Voltage ( $V_G$ )	-2.5 V (Typ.)
Gate Current Under RF Drive ( $I_{G\_DRIVE}$ )	See plots p. 7

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions.

### Electrical Specifications

Test conditions unless otherwise noted: 25 °C,  $V_D = 28$  V,  $I_{DQ} = 225$  mA,  $V_G = -2.5$  V Typ, Pulsed  $V_D$ : PW = 100  $\mu$ s, DC = 10 %

Parameter	Min	Typical	Max	Units
Operational Frequency Range	2.7		3.7	GHz
Small Signal Gain		32		dB
Input Return Loss		> 15		dB
Output Return Loss		> 10		dB
Output Power at Saturation ( $P_{IN} = 18$ dBm)		42.5		dBm
Power-Added Efficiency ( $P_{IN} = 18$ dBm)		> 50		%
Gain Temperature Coefficient		-0.05		dB/°C
Power Temperature Coefficient		-0.005		dBm/°C

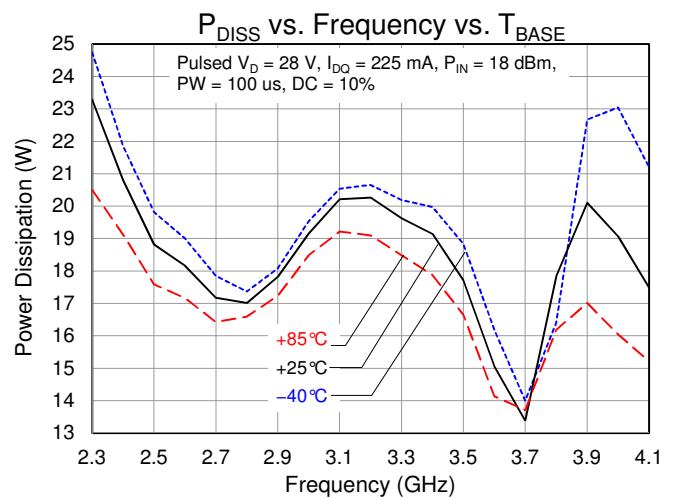
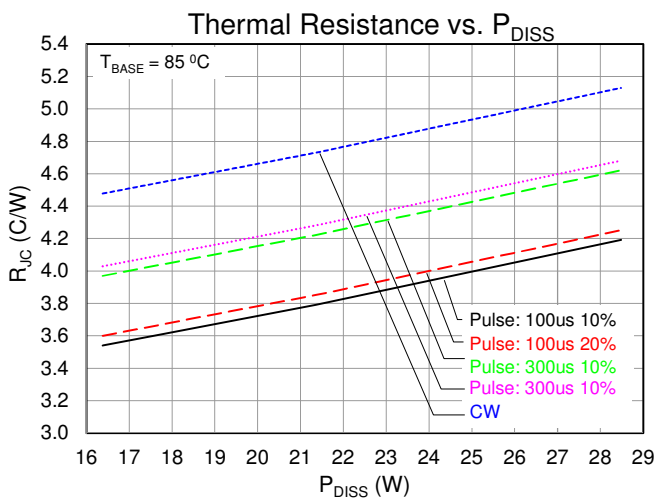
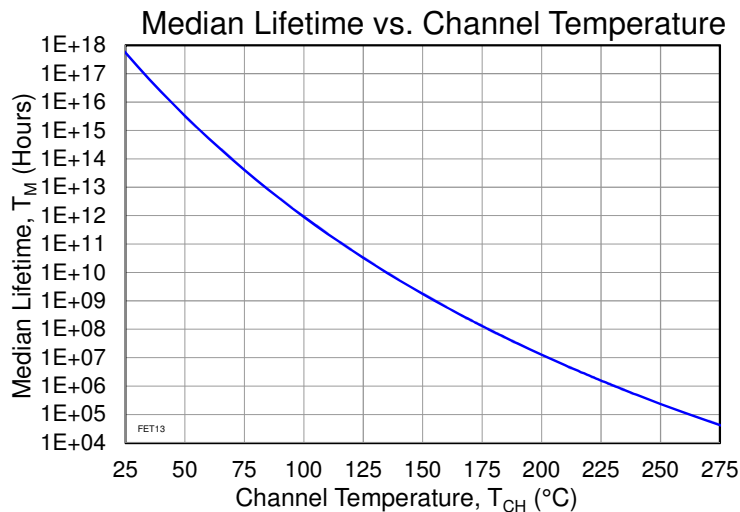
## Thermal and Reliability Information

Parameter	Test Conditions	Value	Units
Thermal Resistance ( $\theta_{JC}$ ) <sup>(1)</sup>	$T_{BASE} = 85^\circ\text{C}$ , $V_D = 28\text{ V Pulse}$ $PW = 100\text{ us}$ , $DC = 10\%$	3.65	$^\circ\text{C/W}$ $^\circ\text{C}$
Channel Temperature ( $T_{CH}$ ) (Under RF drive)	At Freq = 3 GHz, $P_{IN} = 18\text{ dBm}$ : $I_{DQ} = 225\text{ mA}$ , $I_{D\_Drive} = 1330\text{ mA}$ $P_{OUT} = 42.7\text{ dBm}$	153	$^\circ\text{C}$
Median Lifetime ( $T_M$ )	$P_{DISS} = 18.6\text{ W}$	1.26E+9	Hrs

Notes:

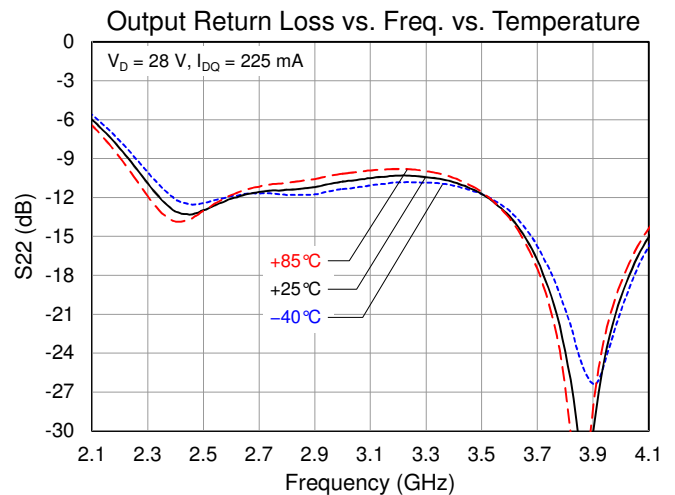
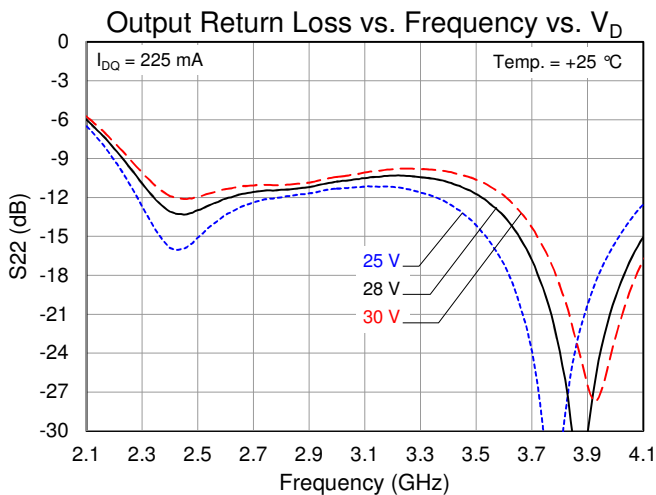
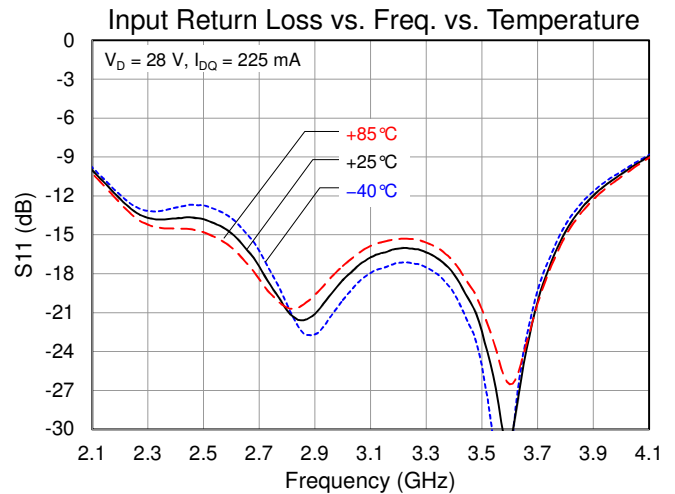
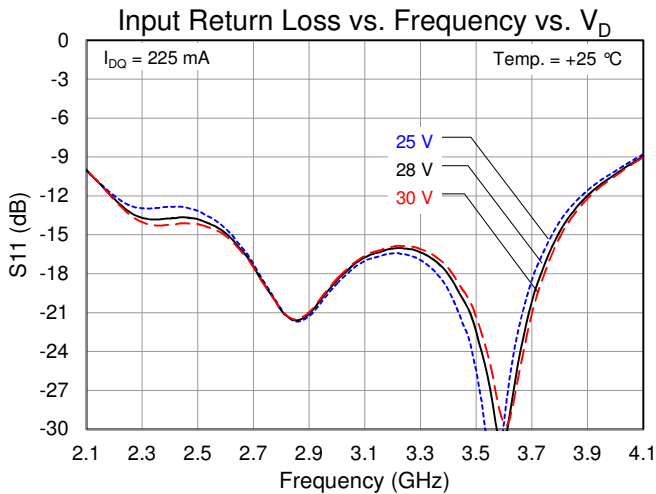
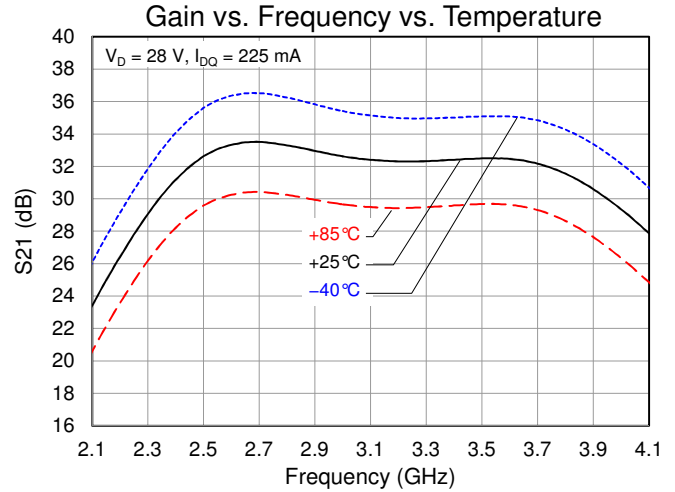
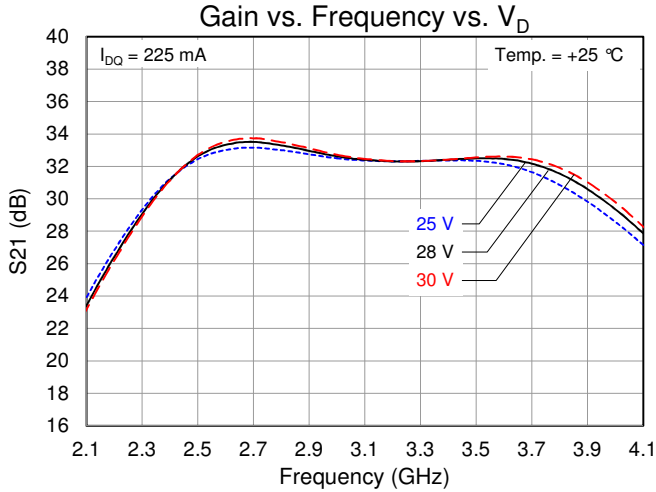
1. Thermal resistance measured to back of package.

Test Conditions:  $V_D = 40\text{ V}$ ; Failure Criteria = 10% reduction in  $I_{D\_MAX}$



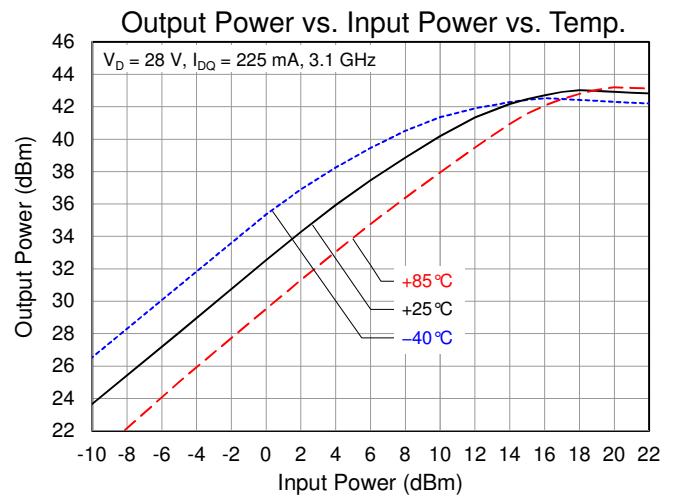
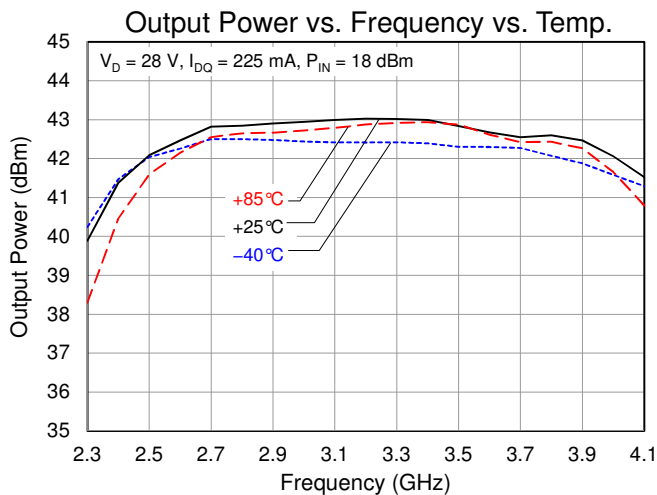
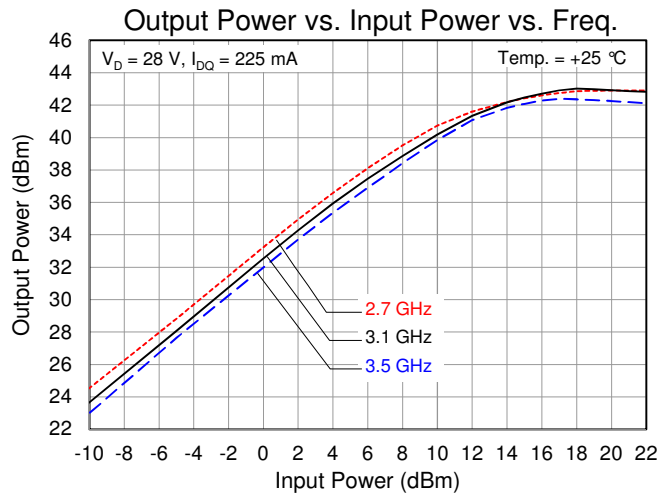
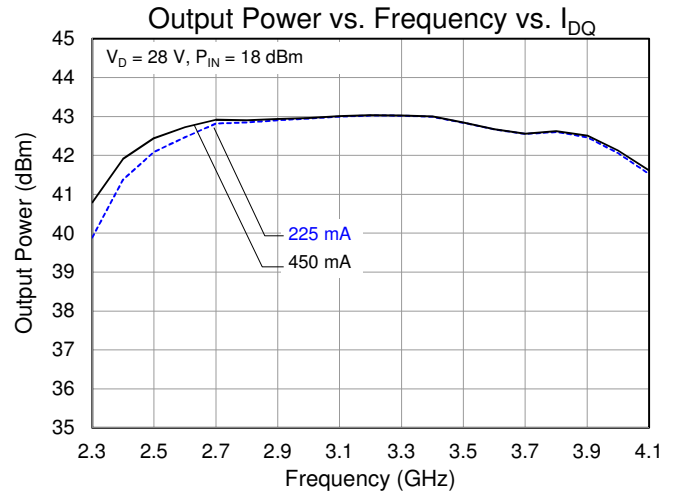
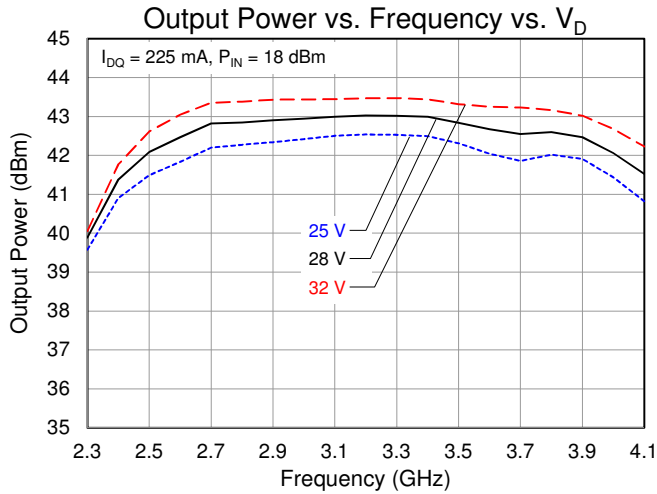
### Typical Performance: Small Signal

Condition: CW



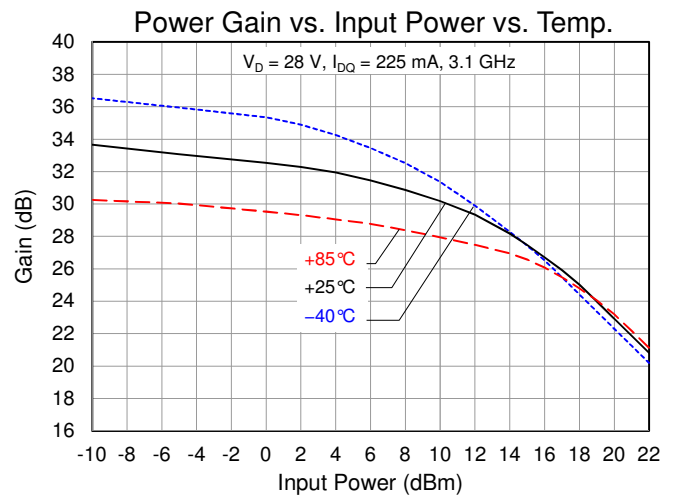
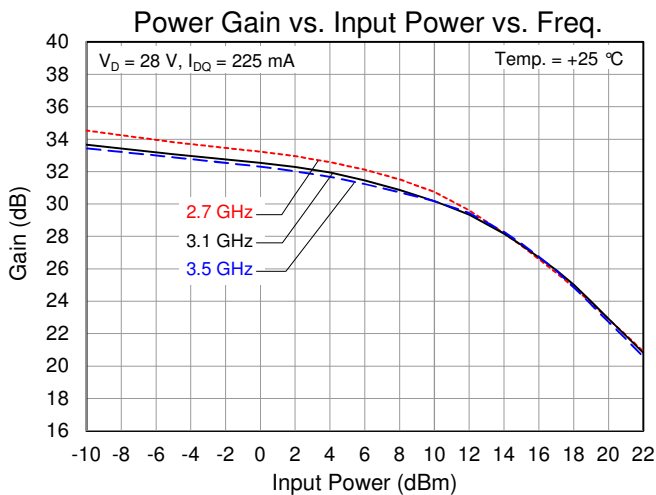
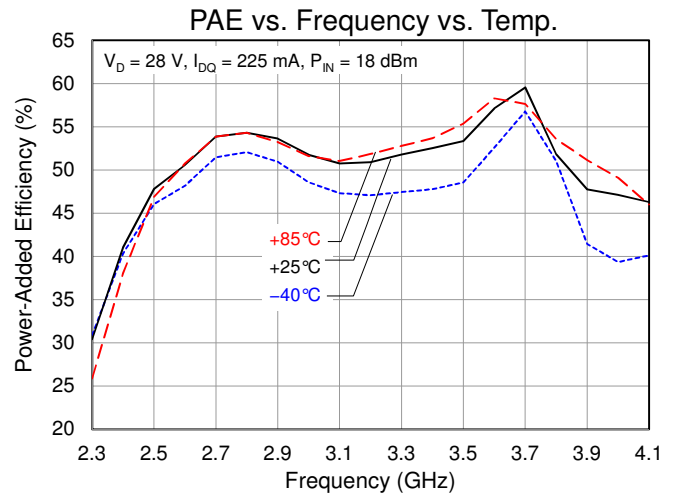
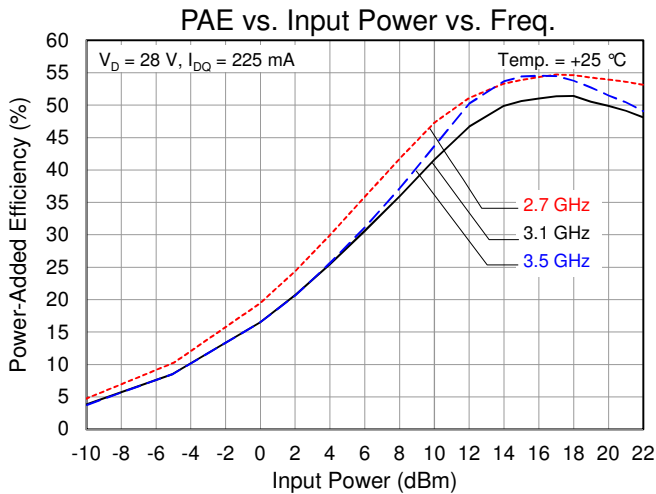
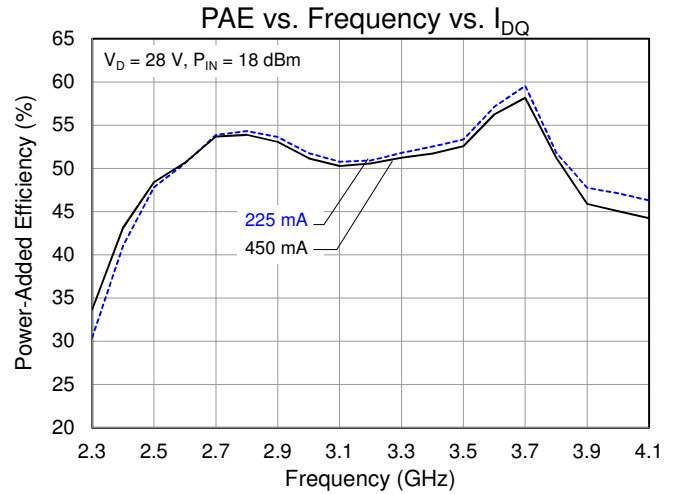
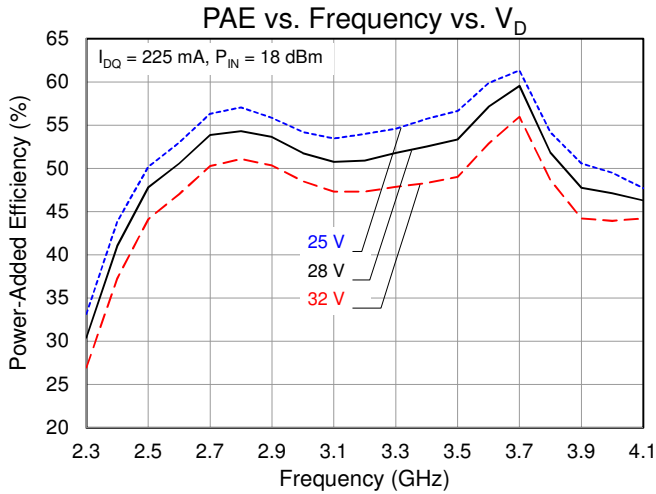
### Typical Performance: Large Signal

Condition: Pulsed  $V_D$ , Pulse Width = 100 us, Duty Cycle = 10%



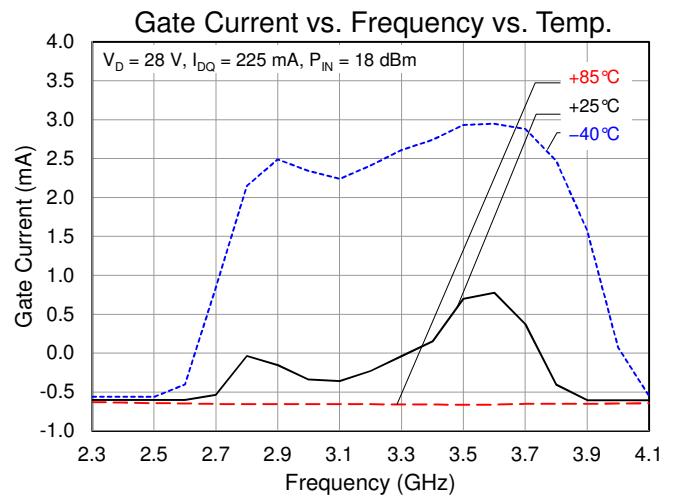
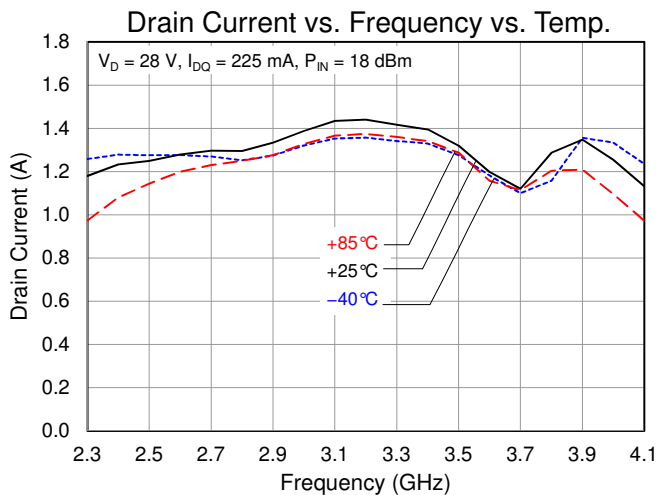
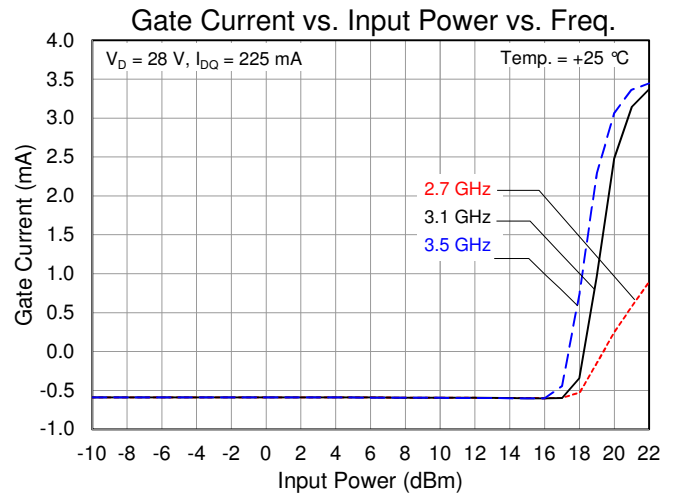
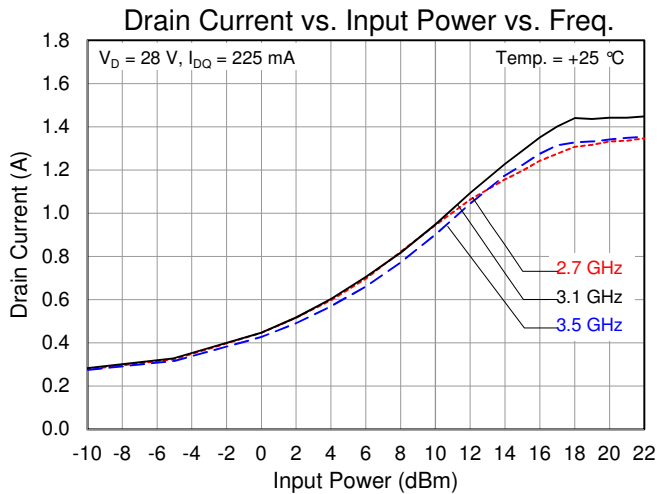
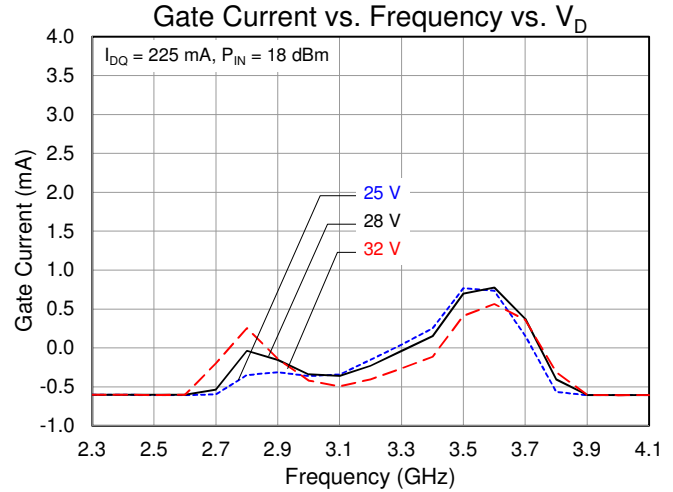
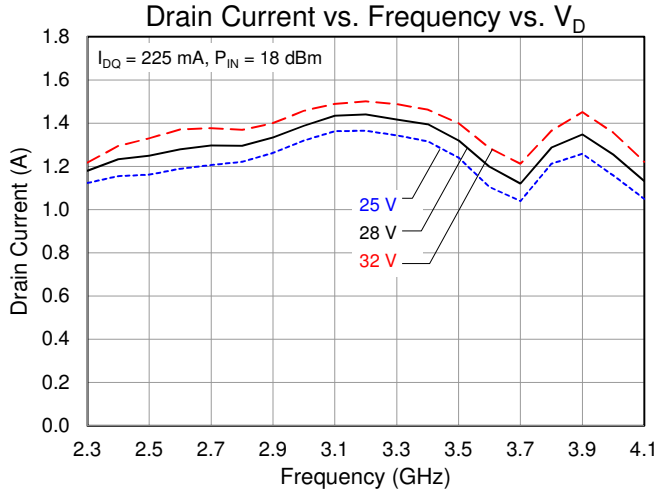
### Typical Performance: Large Signal

Condition: Pulsed  $V_D$ , Pulse Width = 100 us, Duty Cycle = 10%

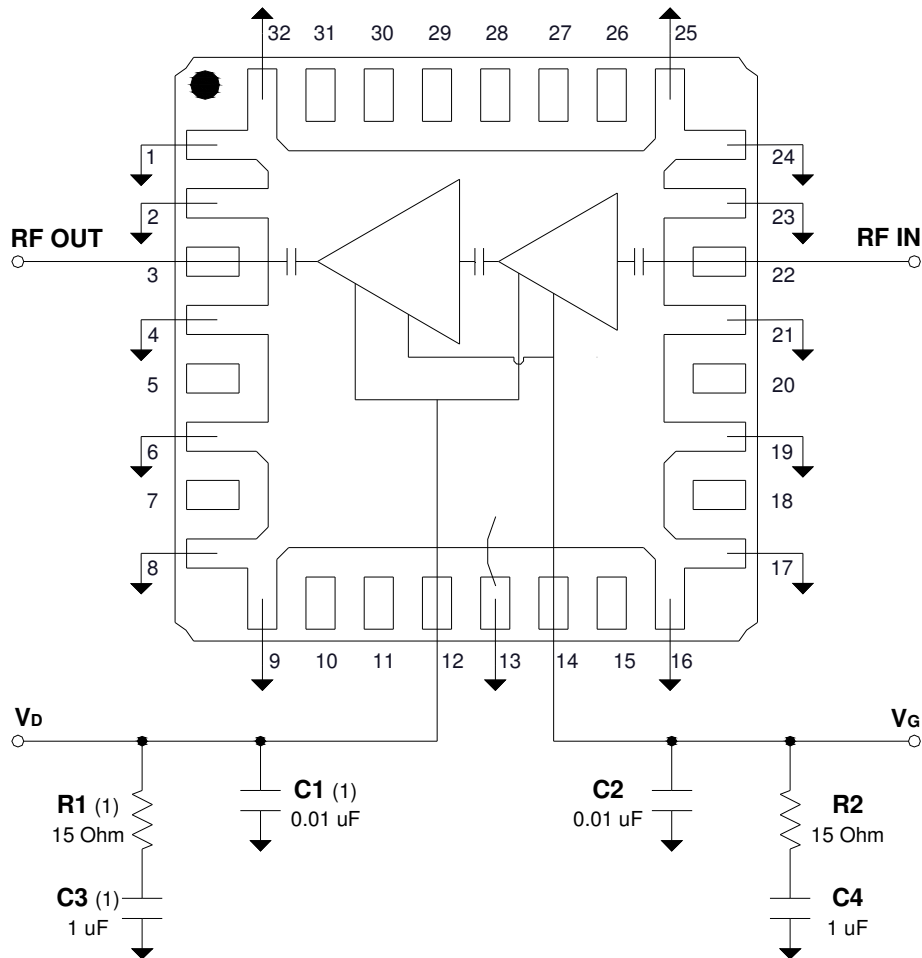


### Typical Performance: Large Signal

Condition: Pulsed  $V_D$ , Pulse Width = 100 us, Duty Cycle = 10%



## Applications Information



Notes:

1. Remove if pulsing on drain

### Bias-up Procedure

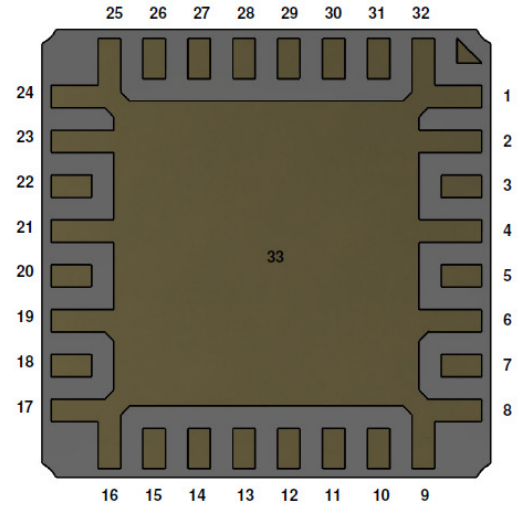
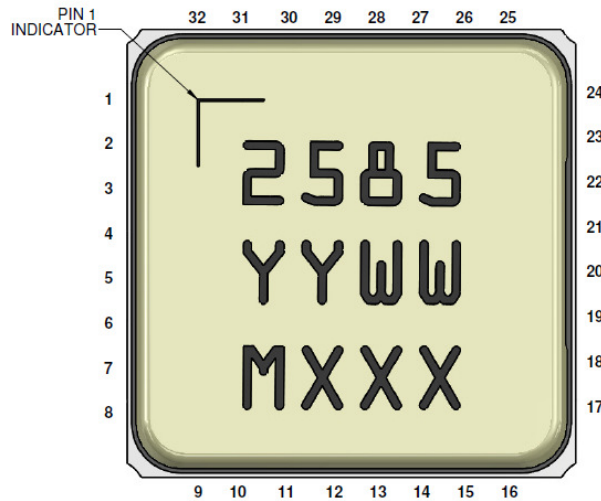
1. Set  $I_D$  limit to 1.53 A,  $I_G$  limit to 8 mA
2. Apply  $-5$  V to  $V_G$
3. Apply  $+28$  V to  $V_D$ ; ensure  $I_{DQ}$  is approx. 0 mA
4. Adjust  $V_G$  until  $I_{DQ} = 225$  mA ( $V_G \sim -2.5$  V Typ.).
5. Turn on RF supply

### Bias-down Procedure

1. Turn off RF supply
2. Reduce  $V_G$  to  $-5$  V; ensure  $I_{DQ}$  is approx. 0 mA
3. Set  $V_D$  to 0 V
4. Turn off  $V_D$  supply
5. Turn off  $V_G$  supply



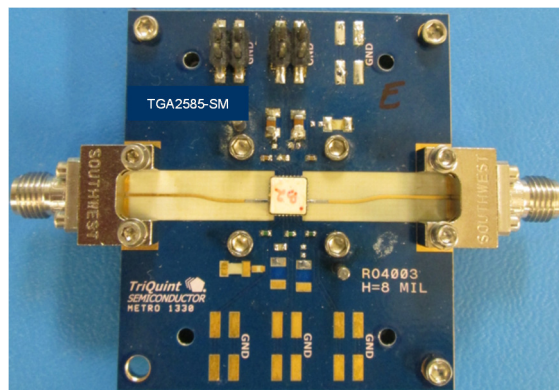
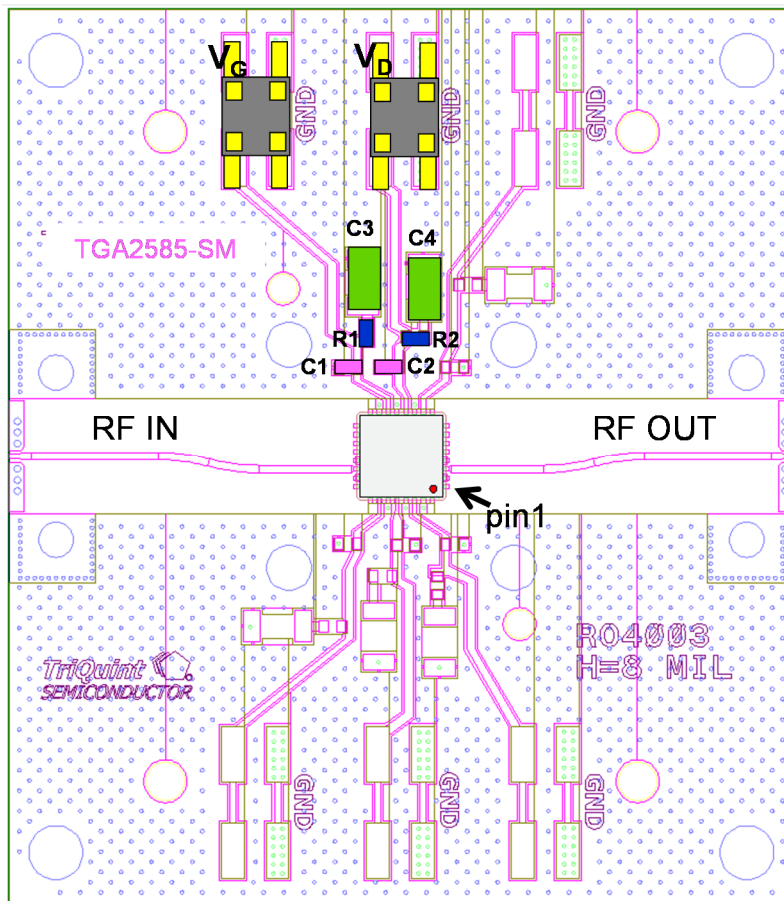
## Pin Layout



## Pin Description

Pin No.	Symbol	Description
1, 3-4, 6, 8-9, 13, 16-17, 19, 21, 23-25, 32	GND	Connected to ground paddle (pin 33); must be grounded on PCB
3	RF OUT	Output; matched to 50 $\Omega$ ; DC blocked
5, 7, 10-11, 15, 18, 20, 26-31	NC	No connection
12	DRAIN	Drain voltage; bias network is required; see recommended Application Information on page 8
14	GATE	Gate voltage; bias network is required; see recommended Application Information on page 8
22	RF IN	Input; matched to 50 $\Omega$ ; DC blocked
33	GND	Ground Paddle. Multiple vias should be employed to minimize inductance and thermal resistance.

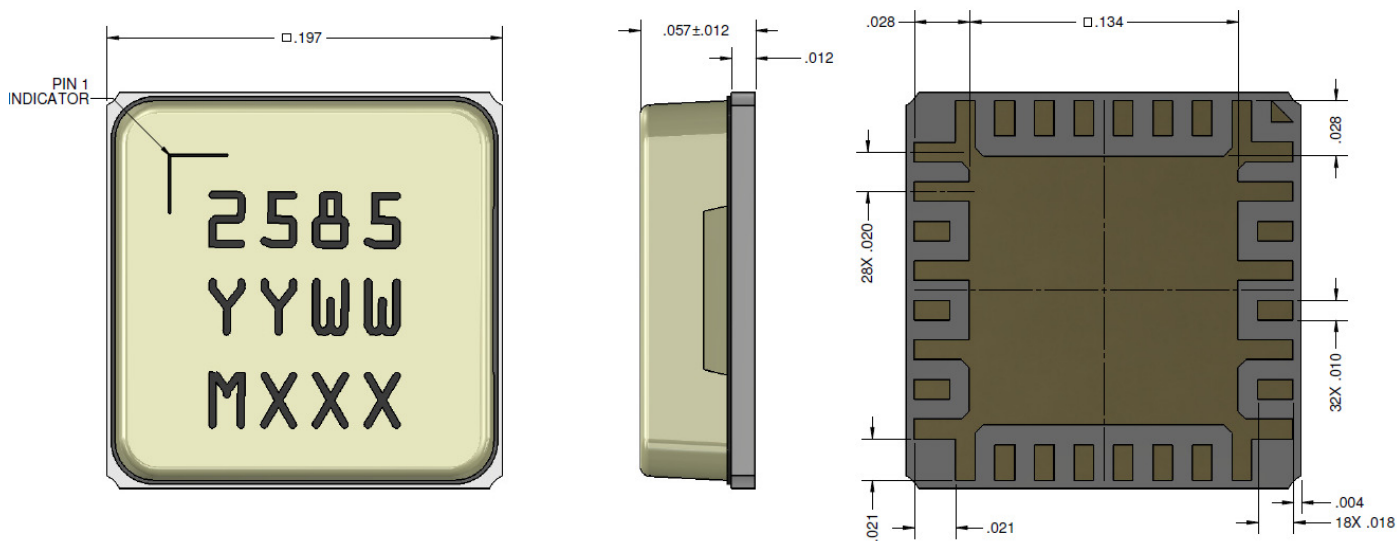
## Evaluation Board



## Bill of Material

Reference Des.	Value	Description	Manuf.	Part Number
C1, C2	0.01 $\mu$ F	Cap, 0402, 50 V, 10%, X7R	Various	
C3, C4	1 $\mu$ F	Cap, 0805, 50 V, 10%, X7R	Various	
R1, R2	15 Ohm	Res, 0402, 5%	Various	

**Mechanical Information**



Units: inches

Tolerances: unless specified

x.xx = ± 0.01

x.xxx = ± 0.005

Materials:

Base: Ceramic

Lid: Plastic

All metalized features are gold plated

Part is epoxy sealed

Marking:

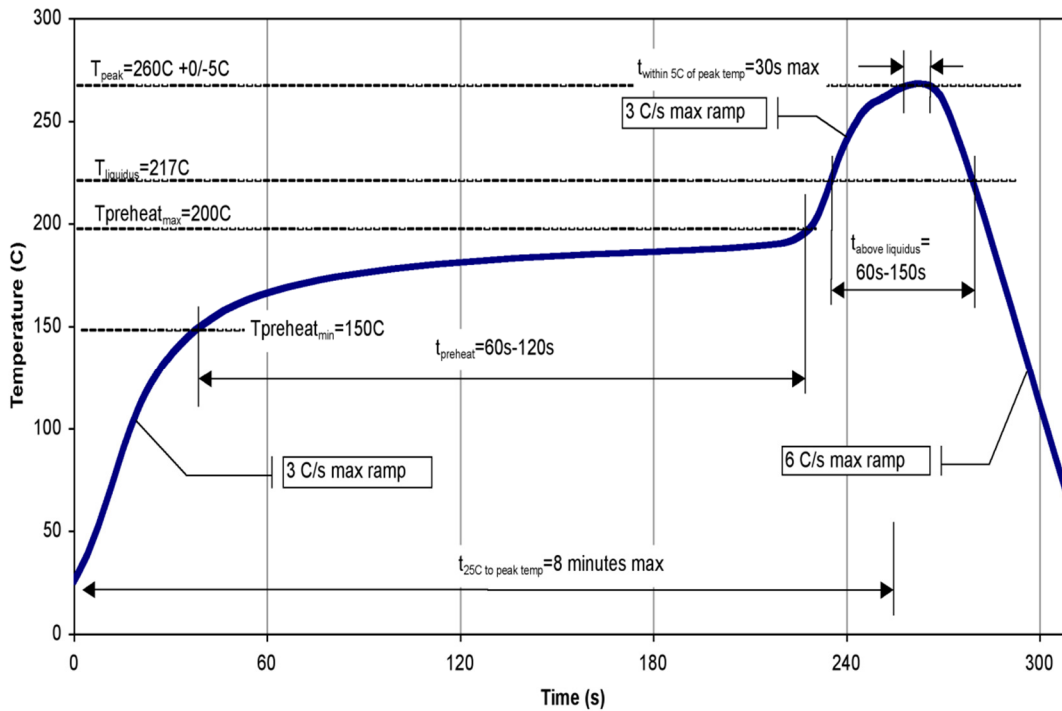
2583: Part number

YY: Part Assembly year

WW: Part Assembly week

MXXX: Batch ID

**Recommended Soldering Temperature Profile**



## Product Compliance Information

### ESD Sensitivity Ratings



Caution! ESD-Sensitive Device

ESD Rating: TBD  
Value: TBD  
Test: Human Body Model (HBM)  
Standard: JEDEC Standard JESD22-A114

### MSL Rating

Level TBD at TBD °C convection reflow  
The part is rated Moisture Sensitivity Level TBD at TBD °C  
per JEDEC standard IPC/JEDEC J-STD-020.

### ECCN

US Department of Commerce: EAR99

### Solderability

Compatible with the latest version of J-STD-020, Lead-free solder, 260 °C

### RoHS Compliance

This part is compliant with EU 2002/95/EC RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment).

This product also has the following attributes:

- Lead Free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C<sub>15</sub>H<sub>12</sub>Br<sub>4</sub>O<sub>2</sub>) Free
- PFOS Free
- SVHC Free

## Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations, and information about TriQuint:

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Email: [info-sales@triquint.com](mailto:info-sales@triquint.com)

Tel: +1.972.994.8465  
Fax: +1.972.994.8504

For technical questions and application information: Email: [info-products@triquint.com](mailto:info-products@triquint.com)

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